# **MAZWxxxHG Series**

## Silicon planar type

For surge absorption circuit

#### ■ Features

• Two elements anode-common type

### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                 | Symbol           | Rating      | Unit |  |
|---------------------------|------------------|-------------|------|--|
| Total power dissipation * | P <sub>tot</sub> | 150         | mW   |  |
| Junction temperature      | $T_{j}$          | 150         | °C   |  |
| Storage temperature       | $T_{stg}$        | -55 to +150 | °C   |  |

Note) \*: P<sub>tot</sub> = 150 mW achieved with a printed circuit board.

#### Package

Code

SSSMini3-F2

- Pin Name
  - 1: Cathode 1
  - 2: Cathode 2
  - 3: Anode 1, 2

#### ■ Internal Connection



### ■ Common Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

| Parameter                       | Symbol          |                | Conditions        | Min   | Тур | Max | Unit |
|---------------------------------|-----------------|----------------|-------------------|---|-----|-----|------|
| Zener voltage *                 | Vz              | $I_Z$          | Specified value — |   |     |     | V    |
| Zener rise operating resistance | R <sub>ZK</sub> | $I_Z$          | Specified value   | Refer to the list of the electrical characteristics |     |     | Ω    |
| Zener operating resistance      | R <sub>Z</sub>  | $I_Z$          | Specified value   | within part n                                       |     | Ω   |      |
| Reverse current                 | $I_R$           | V <sub>R</sub> | Specified value   |   |     |     | μΑ   |

Note) 1. Measuring methods are based JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage is ±10 kV

Test method: IEC1000-4-2 (C = 150 pF, R = 330  $\Omega$ , Contact discharge: 10 times)

3. \*: The temperature must be controlled 25°C for  $V_Z$  mesurement.

 $V_Z$  value measured at other temperature must be adjusted to  $V_Z$  (25°C)

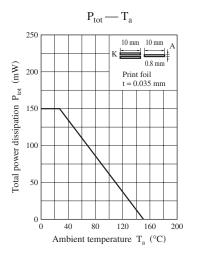
 $V_Z$  guaranted 20 ms after current flow.

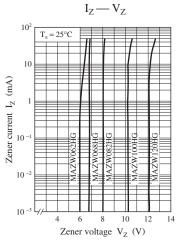
#### ■ Electrical characteristics within part numbers $T_a = 25^{\circ}C \pm 3^{\circ}C$

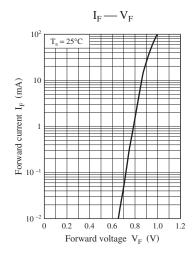
|             | Zener voltage                |      |                     | Reverse current (DC) |                 | Zener operating resistance |                              |                            |    |
|-------------|------------------------------|------|---------------------|----------------------|-----------------|----------------------------|------------------------------|----------------------------|----|
| Part number | rt number V <sub>Z</sub> (V) |      | I <sub>R</sub> (μA) |                      | $R_{Z}(\Omega)$ | $R_{ZK}(\Omega)$           | Marking symbol               |                            |    |
|             | Min                          | Nom  | Max                 | I <sub>Z</sub> (mA)  | Max             | V <sub>R</sub><br>(V)      | I <sub>Z</sub> = 5 mA<br>Max | $I_Z = 0.5 \text{ mA}$ Max |    |
| MAZW062HG   | 5.8                          | 6.2  | 6.6                 | 5                    | 0.2             | 4                          | 50                           | 100                        | 62 |
| MAZW068HG   | 6.4                          | 6.8  | 7.2                 | 5                    | 0.1             | 4                          | 30                           | 60                         | 68 |
| MAZW082HG   | 7.7                          | 8.2  | 8.7                 | 5                    | 0.1             | 5                          | 30                           | 60                         | 82 |
| MAZW100HG   | 9.4                          | 10.0 | 10.6                | 5                    | 0.05            | 7                          | 30                           | 60                         | 10 |
| MAZW120HG   | 11.4                         | 12.0 | 12.7                | 5                    | 0.05            | 9                          | 30                           | 60                         | 12 |

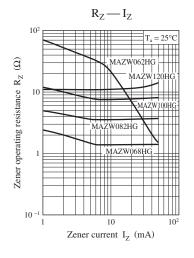
Note) 1. The  $V_Z$  value is the one after power application for 20 ms at  $T_a$  = 25°C.

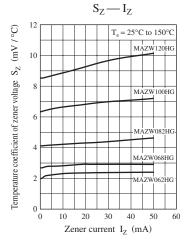
2. The zener voltage temperature coefficient is the one for  $T_j$  = 25°C to 150°C.

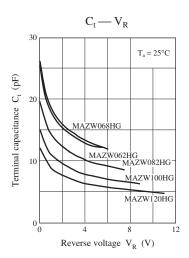






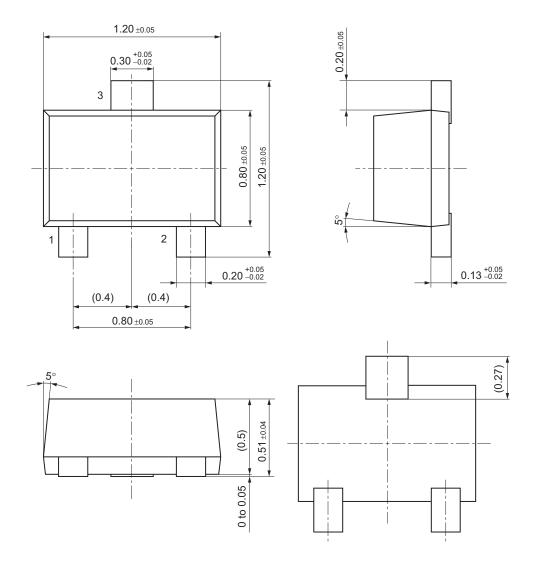






# SSSMini3-F2

Unit: mm



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